

INCHANGE SEMICONDUCTOR

isc N-Channel MOSFET Transistor

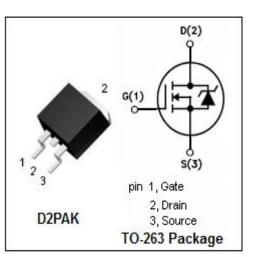
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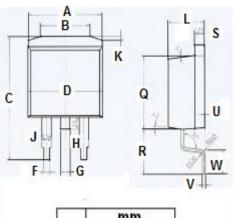
FEATURES

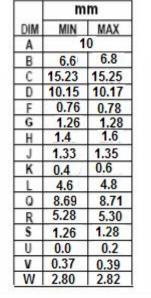
- With TO-263(D2PAK) packaging
- Uninterruptible power supply
- High speed switching
- · Hard switched and high frequency circuits
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operationz

APPLICATIONS

Switching applications







ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{DSS}	Drain-Source Voltage	75	V	
V _{GSS}	Gate-Source Voltage	±20	V	
ID	Drain Current-Continuous@T_c=25 $^{\circ}\text{C}$ T_c=100 $^{\circ}\text{C}$	230 160	А	
I _{DM}	Drain Current-Single Pulsed	910	A	
PD	Total Dissipation	370	W	
Tj	Operating Junction Temperature	-55~175	°C	
T _{stg}	Storage Temperature	-55~175	°C	

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT	
Rth(ch-c)	Channel-to-case thermal resistance	0.4	°C /W	
Rth(ch-a)	Channel-to-ambient thermal resistance	40	°C/W	

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ELECTRICAL CHARACTERISTICS

$T_{\text{C}}\text{=}25^{\circ}\!\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 0.25mA	75			V
V _{GS} (th)	Gate Threshold Voltage	V _{DS} =±20V; I _D =0.25mA	2		4	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =140A		2.3	3.0	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±20V;V _{DS} =0V			±0.1	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 75V; V _{GS} = 0V@Tc=25℃ Tc=125℃			20 250	μA
V _{SDF}	Diode forward voltage	I _{SD} =140A, V _{GS} = 0 V			1.3	v



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